Transport through multiply connected quantum wires

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W e study transport through multiply coupled carbon nano-tubes (quantum wires) and compute the conductances through the two wires as a function of the two gate voltages g_1 and g_2 controlling the chemical potential of the electrons in the two wires. We nd that there is an equilibrium cross-conductance, and we obtain its dependence on the tem perature and length of the wires. The e ective action of the model for the wires in the strong coupling (equivalently C oulom b interaction) lim it can also be mapped to a system of capacitively coupled quantum dots. We thus also obtain the conductances for identical and non-identical dots. These results can be experimentally tested.

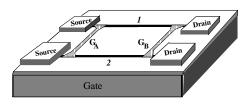
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I. IN TRODUCTION

Transport in one-dimensional system s (quantum wires) has continued to attract interest in the last decade. This has been mainly due to the fabrication of novel onedimensional materials like single-walled carbon nanotubes, besides the more standard quantum wires obtained by gating sem i-conductors. Moreover, attention has been attracted by the evidence for Luttinger liquid behavior in the non-linear transport measurements on these carbon nano-tubes [1{3]. This has led to an upsurge of theoretical work [4{6] on transport through carbon nano-tubes.

Transport m easurem ents involving m ore than one carbon nanotube can show even m ore dram atic deviations from Ferm i liquid behaviour. For instance, the predictions [7] for crossed carbon nano-tubes have been experim entally veri ed [8]. Further predictions [9] have been m ade for longer contacts leading to C oulom b drag as well.

In this paper, we study a system of two carbon nanotubes with a slightly di erent geom etry. The aim is to understand the phenom ena of resonant tunneling through coupled carbon nanotubes. W e start with a system of two w ires with density-density couplings operating at the two ends of both the wires [10]. This geometry is also relevant in the study of entangled electrons, where a superconductor (source of entangled electrons) is weakly coupled to the wires and the consequent nonlocal correlation is m easured at the two edges [11]. The experim ental situation that we wish to analyze is given in Fig.(1). The carbon nano-tube wires are between the source and the drain and the two oating gates above the wires provide a strong capacitive coupling between the two wires at both ends. W e will see later that the sam e setup can also be thought of as a set of two quantum dots in parallel, at least in the strong interaction lim it, where the densitydensity couplings between the wires them selves are the tunnel barriers responsible for form ing the dot. (Wew ill see this analogy explicitly in the e ective action.)



F IG .1. Carbon nanotube wires 1 and 2 are stretched between the source and the drain. G_A and G_B are the two oating gates which generate a strong capacitive coupling between the two wires at the two ends.

Our aim is to compute the conductance through the two wires as a function of the two gate voltages q_1 and q_2 controlling the density of electrons in wires 1 and 2. W ithout leads, when the electron-electron C oulom b interaction strength is weak, the capacitive coupling between the wires gets renorm alized to zero and the system decouples into two independent wires. The resonant transm ission pattern in this case is well-known and is sim ply the resonant transmission between double barriers. But in the lim it of strong inter-electron interactions, the coupling between the wires grows, and an interesting resonance pattern em erges, W ith the inclusion of leads, we nd that the value of the interaction strength for which the coupling changes from being irrelevant to relevant changes. W ith leads, even stronger inter-electron interactions are needed to access the strong coupling regime. Fortunately, for carbon nano-tubes, the interaction param eter is in this regime, and the interesting resonance pattern that emerges in the strong coupling lim it can be experim entally tested.

In Sec. (II), we show how the system can be modelled in terms of the one-dimensional bosonised Luttinger liquid Lagrangian. In Sec. (III), we obtain the elective action by integrating out all degrees of freedom, except at the coupling points, rstly for a uniform wire without leads. We then show that for identical wires, the system

decouples in term s of sym m etric (+ ') and antisym m etric (1^{0}) combinations of the elds at the coupling points (boundary elds), and we are essentially left with two copies of a wire with back-scattering potentials at the two ends. In the weak Coulomb interaction limit, the back-scattering couplings potentials renorm alise to zero (at very low tem peratures T ! 0 and long wire lengths d! 1). However, for strong Coulom b interactions, the back-scattering potentials turn out to be relevant. At T ! 0 and d ! 1, the wires are 'cut' and there is no transm ission. However, there is still the possiblity of resonant transm ission. W hen m apped back to the originalwires, the conductance maxim a form s an interesting resonance pattern. For non-identical wires, there is a coupling term, which can be treated perturbatively and the change in the pattern of resonance maxim a can be explicitly obtained. In both the cases of strong and weak C oulom b interactions, the conductances through the two wires can be explicitly computed in terms of the new $+^{0}$ and \cdot^{0} elds perturbatively. In the high temperature limit, the tem perature T is the scale of the cuto of the renorm alisation group (RG) equations and the conductances are a function of T. In the low temperature lim it, and for nite length wires, the length of the wire is the RG cut-o , and the length dependences of the conductances can be obtained. Interestingly, we nd that there is a non-zero equilibrium cross-conductance - i.e., there is a non-zero current through one wire caused by a voltage drop across the other wire. Finally, we show that the inclusion of leads changes the value of the interaction parameter where the coupling between the wires changes from being irrelevant to relevant. The resonance patterns do not change due to the inclusion of leads, but the dependence of conductances on the tem perature and the length of the wires, which depend on the RG ow of the coupling strengths do change and we com pute the new conductances.

In Sec. (IV), we show how the elective action in the strong interaction lim it is identical to the action that one would get for two capacitively coupled quantum dots. Hence, we show that our results are also applicable to a system of capacitively coupled quantum dots. Finally in Sec. (V), we conclude with a discussion of how the current model can be extended to multiply coupled wires and multiply coupled dots.

II.THE MODEL

Follow ing R ef. [4], we will assume that the band structure of the carbon nanotube is captured by the onedimensional free ferm ion model given by

$$H_{0} = \begin{array}{c} X & Z \\ H_{0} = & dx v_{F} \left[\begin{array}{c} y \\ R i \end{array} i \right] \left(R \right) \left(R \right)$$
(1)

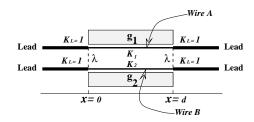


FIG.2. Schem atic diagram of the experimental setup. The wires are modeled as LLs with K $_{i=1;2}$, with the leads having K $_{\rm L}$ = 1. The density-density coupling between the wires is denoted by its strength and the two gate voltages controlling the densities of electrons in the wire are denoted by g_1 and g_2 .

where i = 1;2 refers to the two wires and = ";# refers to the two spins. Coulomb repulsion between the electrons can be approximated as an onsite density-density interaction as follows -

$$H_{int} = \begin{array}{c} X & Z \\ dx & i'' & i\# \end{array}$$
(2)

Here $_{i}(x) = {\stackrel{y}{i}}_{i}$ are the electron densities of the " and # electrons and $_{i} = {}_{Li} e^{ik_{F}x} + {}_{Ri} e^{ik_{F}x}$. The $_{Ri}$ and $_{Li}$ stand for ferm ion elds linearized about the left and right Ferm i points in the ith wire. U sing the standard bosonisation procedure, whereby a ferm ionic theory can be rewritten as a bosonic theory with the identication $_{i} = ({}_{i} = {}^{2}) e^{2i^{n} - i}$, the H am iltonian can be written as

$$H = H_{0} + H_{int} = \sum_{i}^{X} \frac{v_{i}}{2} K_{i} (i)^{2} \frac{1}{K_{i}} (\theta_{x i})^{2}$$
(3)

where = c; are the subscripts for charge and spin degrees of freedom, instead of = ";# since the interaction term mixes them. i are the K lein factors that ensure the anti-commutation relations of the ferm ions. Here K ic (1 + g= $\psi_{\rm f}$)¹⁼², vic $\psi_{\rm f}$ (1 + g= $v_{\rm F}$)¹⁼² and $_{i_{\rm fC}}$ are the elds dual to $_{i_{\rm fC}}$. K i = 1 and $v_{\rm i} = v_{\rm F}$ in the absence of magnetic elds. K ic = 1 for free electrons and K ic < 1 for repulsive e-e interactions. For sim plicity, we will now drop spin indices and work with spinless electrons, and write down the action for the setup in Fig. 1 as

$$S = d [L_{leads} + L_{wires} + L_{coup} + L_{gates}]: (4)$$

The electrons in the leads are free while the electrons in wires 1 and 2 are interacting and they are modelled as Luttinger liquids with Luttinger parameter K $_{\rm iL}$ = 1 and K $_{\rm i}$ = K $_{\rm 1}$; K $_{\rm 2}$ respectively –

$$L_{\text{leads}} + L_{\text{w ires}} = \sum_{i=1}^{X^2} [(L_{\text{leads}})_i + (L_{\text{w ires}})_i]$$

Ζ

$$= \begin{array}{ccccc} X^{2} & Z_{0} & Z_{1} \\ & + & dxL_{i}(i; K_{iL}; v_{F}) \\ & & X^{2} & Z_{d} \\ & + & dxL(i; K_{i}; v_{i}): \end{array}$$
(5)

Here $_{i}$ denotes the (spinless) Luttinger bosons in wires 1 and 2 respectively with the Lagrangian densities

$$L_{i}(i;K_{i};v_{i}) = (1=2K_{i})[(1=v_{i})(\theta_{t-i})^{2} (V_{i})(\theta_{x-i})^{2}]:$$
(6)

The Lagrangian for the coupling between the wires is given as

$$L_{coup} = \int_{1}^{Z_{+1}} dx \left[1 + 1 (x) + 2 (x) (x) + \frac{1}{2} - 1 (x) + 2 (x) (x + d) \right]$$
$$= \frac{1}{(-)^{2}} \cos(2^{p} - \frac{1}{1}) \cos(2^{-1} - \frac{1}{2})$$
$$+ \cos(2^{p} - \frac{2}{1} + 2k_{F} d) \cos(2^{-1} - \frac{2}{2} + 2k_{F} d) ; (7)$$

where $_{i}$ are the densities of the electrons, and in terms of the bosonic elds, they are given by

$$_{i}(\mathbf{x}) = \frac{1}{\mathbf{p}-\mathbf{0}_{x}} \mathbf{0}_{x} \mathbf{0}_{x} \mathbf{0}_{x} + \frac{1}{\mathbf{m}} \cos(2^{\mathbf{p}-\mathbf{0}_{x}} \mathbf{0}_{x}) \mathbf{0}_{x} \mathbf{0}_{x} \mathbf{0}_{x} \mathbf{0}_{x}$$
 (8)

Here is an infra-red regulator and we have set K lein factors to 1 (which is su cient for the correlation functions we compute in this paper, although in general with two wires, one has to be careful.) The gate voltage that couples to the electrons densities in the two dots is modeled by the following term in the action -

$$L_{gates} = \begin{cases} X^2 & Z_{d} \\ g_{i} & dx \\ i = 1 \end{cases} \begin{pmatrix} X^2 & g_{i} \\ p = 1 \end{pmatrix} \begin{pmatrix} X^2 \\ p = 1 \end{pmatrix} \begin{pmatrix} g_{i} \\ i \end{pmatrix} \begin{pmatrix} 2 \\ i \end{pmatrix} \begin{pmatrix} 1 \\ i \end{pmatrix} (9)$$

III. THE EFFECTIVE ACTION

Uniform wire with no leads

We rst analyse the model of a uniform quantum wire with $$\mathbf{Z}$$

$$S = d (L_{w ires} + L_{coup} + L_{gates}); \qquad (10)$$

where $L_{w \text{ ires}} = P_{2} R_{1}$ the Lagrangian for the coupling between the wires L_{coup} and the coupling between the wires and the gates, L_{gate} , are both functionals only of the elds at the boundaries (i.e. at x = 0 and x = d). Hence, even in $L_{w \text{ ires}}$ (which is a functional of the bulk elds), it is convenient for further calculations to integrate out all degrees of freedom except at the coupling points, x = 0 and x = d, and obtain an e ective action [13] in term softhe boundary elds given by

$$(S_{eff})_{0} = \overset{Z}{d} \overset{X^{2}}{\underset{i=1}{\overset{i=1}{X^{2}}} (L_{w \text{ ires}})_{i}$$

$$= \overset{X^{2}}{\underset{i=1}{\overset{1}{X^{2}}} \frac{1}{2K_{i}} \overset{Z}{j!} j! j! (\binom{\gamma_{1}}{i})^{2} + \binom{\gamma_{2}}{i}^{2}) d!$$

$$+ \overset{X^{2}}{\underset{i=1}{\overset{1}{2K_{i}}} \frac{1}{e^{k_{i}d}} \frac{j! j}{e^{k_{i}d}} \overset{n}{e^{k_{i}d}} (e^{k_{i}d} + e^{-k_{i}d})$$

$$(\binom{\gamma_{1}}{i}^{2} + \binom{\gamma_{2}}{i}^{2}) \quad 4^{\gamma_{1}} \overset{\circ}{\underset{i=1}{\overset{\circ}{X^{2}}}} d! : (11)$$

The Fourier transformed tilde elds are dened by ${}_{i}^{1;2}() = {}_{!_{n}} e^{i!_{n}} {}_{i}^{-1;2}(!_{n})$: In the high frequency or equivalently, high temperature limit, (T $hv_{i}=k_{B}d$), (S_{eff})₀ reduces to

$$(S_{eff})_{0}^{ht} = \frac{X^{2}}{\sum_{i=1}^{K} \frac{1}{K_{i}}} \frac{Z}{j! j({\binom{1}{i}}^{2} + {\binom{2}{i}}^{2})d!} : (12)$$

In the low tem perature lim it (T $hv_i=k_B d$), the densitydensity coupling at the two ends of each wire are seen coherently by the electrons and the total electric action reduces to

$$S_{eff} = (S_{eff})_{0}^{lt} + d [L_{coup} + L_{gates}]$$

$$= \frac{X^{2}}{\sum_{i=1}^{i=1} \frac{1}{2K_{i}}} j! j((\sum_{i=1}^{i})^{2} + (\sum_{i=1}^{i=2})^{2}) d!$$

$$+ d \sum_{i=1}^{i=1} \frac{U_{i}}{2} (\sum_{i=1}^{2} \sum_{i=1}^{1})^{2}$$

$$+ L_{coup} + L_{gates}]: (13)$$

The $U_i = hv_i = K_i d$ are the mass terms that suppress charge uctuations on the wires and are responsible for the C oulom b blockade (CB) through the wires. In this paper we consider the symmetric case where $_1 = _2 =$ (say).

For further analysis, it is convenient to de ne the follow ing variables -

$$_{i} = \frac{\frac{1}{i} + \frac{2}{i}}{2} + \frac{k_{\rm F} d}{2}; \quad N_{i} = \frac{\frac{2}{i} + \frac{1}{i}}{P - \frac{1}{i}} + \frac{k_{\rm F} d}{P} : \quad (14)$$

In term s of these variables the coupling part of the action can be written as

$$L_{coup} = - [\cos 2^{p} (_{1} + _{2}) \cos 2^{p} (_{N_{1}} + _{N_{2}}) + \cos 2^{p} (_{1} _{2}) \cos 2^{p} (_{N_{1}} N_{2})]; \quad (15)$$

The expression for L_{coup} in terms of the new elds suggests that we can diagonalise the problem by introducing

the follow ing sym m etric and anti-sym m etric com bination of elds – $\ensuremath{\mathsf{-}}$

$$=$$
 1 2; N $=$ N 1 N2 : (16)

Thus, the total action (in the low T lim it) can be written in terms of these new elds as

$$S_{eff} = \begin{bmatrix} Z & X & [\frac{U_{eff}}{2} (N & N_0)^2] \\ & & = +; \end{bmatrix}$$

+ $\frac{U_1 & U_2}{4} N_+ N_+$
+ $\frac{U_1 & U_2}{4} \sum_{n=1}^{n} [\cos 2^{n} - \cos N_n];$ (17)

where $U_{eff} = (U_1 + U_2)=4$; $U_i = U_i$ and S_1 , N_{0+} and N_0 are given by

$$S_{1} = \frac{1}{2} \frac{X}{I_{n}} \qquad (N_{+})^{2} + \frac{1}{4} (\gamma_{+})^{2} + (N_{-})^{2} + \frac{1}{4} (\gamma_{-})^{2} \qquad (18)$$

and

$$N_{0} = \frac{k_{F} d (U_{1} \quad U_{2}) \quad (q \quad q_{2})}{(=2) (U_{1} + U_{2})} :$$
(19)

Thus, from Eq.(17), we see that when $U_1 = U_2$, we have successfully mapped the problem of two density coupled quantum wires to a pair of \decoupled" quantum wires with double barriers. When $U_1 \in U_2$ but is small, the two wires interact weakly. It is also possible to identify e ective Luttinger liquid parameters for the ` ⁰ wires from U_{eff} (for $U_1 = U_2$) by writing it as $U_{eff} = U_{eff} =$ $hv=K_{eff}d$ and we nd that $K_{eff} = 4K_1K_2 = (K_1 + K_2)$ for both the `+ ' and ` ' wires, since both of them have the sam e U_{eff} .

Note that for K $_1 = K_2 = K$, K $_{eff} = 2K$. Hence, the interaction parameter has doubled [7]. The $+^{0}$ and \cdot^{0} wires are 'free' when K = 1=2, and the quasi-particles have repulsive interactions for K < 1=2 and attractive interactions for K > 1=2.

(a) Case of
$$U_1 = U_2 = U$$
:

When $U_1 = U_2$ the coupling term between the '+' and ' elds drops from the elds ective action and the action is exactly identical to the elds ective action of a decoupled pair of quantum wires, each with two barriers, in one dimension [13]. The action remains invariant under the following transform ations

$$! + \frac{p}{2}; N ! 2N_0 N ; (20)$$

when N₀ is tuned to be a half-integer by tuning the gate voltages g_1 and g_2 . This tuning of gate voltages corresponds to certain special points in the $(g_1;g_2)$ plane where resonance transport of electrons through each of the wires takes place.

The conductance matrix for the two-wire system . in the linear response regime, can be written as

$$G = \begin{array}{c} G_{11} & G_{12} \\ G_{21} & G_{22} \end{array} ; \qquad (21)$$

where G_{ii} is the conductance through each wire due to the voltage across the same wire and G_{ij} is the crossconductance – the conductance in wire i due to the voltage drop in wire j. Note that the density-density couplings at the two ends of the wires can be thought to be the source of 'entanglem ent' of the previously uncorrelated electrons in wires 1 and 2. The cross-conductance G_{12} is a measure of this entanglem ent.

By transforming to the 4° and 3° wires, we can compute G explicitly since they are just the conductances for uncoupled wires with two barriers each. Moreover, since G can be written in terms of the currents $j = j_1$, j_2 , we not that

$$G_{+}(g_{1} + g_{2}) = G_{11} + G_{22} + G_{12} + G_{21} (g_{1};g_{2})$$

$$G (g_1 g_2) = G_{11} + G_{22} G_{12} G_{21} (g_1;g_2);$$
 (22)

from which we can obtain

$$G_1 + G_2 = G_+ + G_- = G_-$$
 (23)

$$G_{12} + G_{21} = G_{+} \quad G :$$
 (24)

Note that $G_{12} + G_{21} \notin 0$, as long as $G_+ \notin G_-$. Thus unlike in the case of the singly crossed carbon nanotubes [7], where the cross-conductance G_{12} was a nonequilibrium e ect and vanished in the linear response regime, here, the cross-conductance is an equilibrium phenom ena. It only requires $G_+ \notin G_-$. Since the conductances G_+ and G_- are independently tuned by the gate voltages $g_1 + g_2$ and $g_1 - g_1$, they are equal only if they are both tuned to be equal.

The combined transport through the wires 1 and 2 can now be tuned to resonance when both G₊ and G are tuned to resonance (m axim um), or when one of them is tuned to resonance (sem i-m axim um). It is easy to see that the conductancem axim a through both the dots form a rectangular grid of points in the plane of the gate voltages, when N₀₊ and N₀ are tuned to half integers - i.e.; N₀₊ = n + 1=2 and N₀ = m + 1=2. The values of the appropriate gate voltages, given below,

$$g_2 + g_1 = \frac{2k_F d}{m} (n + \frac{1}{2}) U$$

 $g_2 \quad q = (m + \frac{1}{2}) U$ (25)

are plotted in Fig. 3. The sem im axim a form the two pairs of solid lines and the intersections of the two pairs of lines are the maxim a.

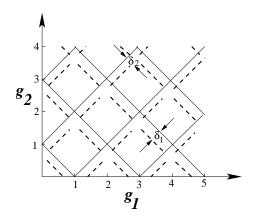


FIG.3. Conductances in the plane of the two gate voltages g_1 . For $U_1 = U_2$, the solid lines represent sem im axim a (4^{0} or $*^{0}$ w ire at resonance) and the crossings represent the maxim a (both w ires at resonance). The dotted line represents sem im axim a (4^{0} or $*^{0}$ w ire at resonance) for $U_1 \notin U_2$. There is no resonance at the crossings of the dotted lines and that region has been left blank.

(i) W eak interaction , weak coupling lim it :

A fler transform ing to the `⁰ w ires, the RG ow of the density-density coupling term is given by

$$\frac{d}{dl} = (1 \quad K_{eff}) : \qquad (26)$$

For weak inter-electron interactions (K $> 1=2 \text{ or K}_{eff} > 1$), the the coupling is irrelevant and it grows smaller as a function of the energy cuto l = ln[() =]. Here,

is an arbitrary high energy scale (say, the inverse of the average inter-particle separation) at which we start the renorm aisation group ow . We are interested in the conductance of the system in the low temperature limit ($T T_d$) where there is coherent transport through both the barriers. The total conductance through the system is given by [14]

$$G = \frac{2e^2}{h} - \frac{1}{2}e^{2} \left(\frac{T}{h}\right)^{2(K_{eff} - 1)} [2 + \cos 2 N_{0+} + \cos 2 N_{0-}]; \quad (27)$$

where, is an arbitrary constant of order unity. Note that the last factor (i.e., factor in square bracket) goes to zero when both the wires are tuned to resonance and then there is perfect conductance through both the wires.

Similarly, the temperature dependence of the total cross-conductance is given by

$$G_{12} + G_{21} = \frac{1}{2} e^{2} \left(\frac{T}{2}\right)^{2 (K_{eff} - 1)} (\cos 2 N_{0+} \cos 2 N_{0-})$$
(28)

in the low temperature limit. Thus, the crossconductance is non-zero unless both wires are at resonance or N₀₊ = N₀ + 2 N and it can be both negative or positive depending on the gate voltages (g_1,g_2) operating on the two wires. Note also that as the tem perature is reduced, the elective barrier strength reduces and hence, perturbation theory is a good approximation. In fact, for T ! 0, the direct conductances are very close to e^2 =h or perfect conductance and the cross-conductances go to zero.

(ii) Strong interaction, strong coupling lim it:

For strong inter-electron interactions (K $_{\rm eff}$ < 1) or K < 1=2, the density-density coupling term is relevant under the RG transform ation. At low energies, the strength of the barriers renorm alize to very large values, and in fact, at zero temperature, or for very long w ires, the 4^{0} and 1^{0} w ires are cut and there is no transmission, except at resonance points. How ever, for nite temperatures and for nite length w ires, there are power law conductances given by [13]

$$G \quad e^{2}t^{2} \left(\frac{T}{-}\right)^{2(1=K_{eff}-1)} \quad G_{12} + G_{21} \qquad (29)$$

where t, of order 1= , is a tunneling am plitude between the cut wires. In this lim it, the system can be considered as a pair of decoupled dots, ($+^{0}$ and \cdot^{0} dots) which are tunnel-coupled to Luttinger wires (see Fig. 6). The density-density couplings which grow them selves act as the barriers form ing the dot.

W ire with leads

Let us now incorporate the leads, by studying the model in Eq.(4). The leads have non-interacting electrons and only the electrons within the length of the wire between the two coupling terms are interacting.

The inclusion of leads essentially changes the renormalisation group ow of the barriers in the two wires [14{16]. To nd the new RG ows, we rst note that even with the inclusion of leads, it is convenient to work with the \pm^{0} and \cdot^{0} elds, where the two wires decouple. In terms of these elds, we nd that the interaction parameters in the leads are also changed and are given by K_L = 2 as compared to K_i = 1. Hence, the leads are no longer Yiree'.

W hen the barrier is at the boundary between the leads and the wire as in our set-up in Figs 1 and 2, the RG equations are given by [16]

$$\frac{d}{dl} = \begin{cases} 8 \\ < (1 \quad K_{eff}^{0}) \quad T \quad T_{d} \\ \\ \vdots \\ (1 \quad K_{l}) \quad T \quad T_{d} \end{cases}$$

where $K_{eff}^{0} = 2 K_{eff} K_{L} = (K_{eff} + K_{L}) = 4K = (K + 1)$ and $T_d = hv = k_B$ d as before. So for the ' 'wires, is relevant if $K_{eff}^{0} < 1$, i.e. K < 1=3 and it is irrelevant for $K_{eff}^{0} > 1$, i.e. K > 1=3.

(i) W eak interaction , weak coupling lim it :

For weak' inter-electron interactions (K $_{\rm eff}^{0} > 1$) or K > 1=3, the density-density coupling term is irrelevant under the RG transform ation. Note that connecting leads to the interacting wires, changes the values of K for which the density-density coupling is irrelevant from K 1=2 to K 1=3. So we observe that even if K < 1=2, but K > 1=3, the density-density coupling still rem ains irrelevant, unlike the case of uniform wire with no leads.

The high temperature conductance scales now with K $_{\rm eff}^0$ instead of K $_{\rm eff}$. But at low temperatures (T T_d) where there is coherent transport through both the barriers, there exists a new feature. The conductance now has both non-trivial temperature and length dependences and is given by

$$G = \frac{2e^2}{h} - \frac{1}{2}e^{2-2} \left(\frac{T}{T_d}\right)^{2(K-L-1)} \left(\frac{T_d}{T_d}\right)^{2(K_{eff}^0-1)}$$

$$(2 + \cos 2 N_{0+} + \cos 2 N_0)$$
(30)

The tem perature dependence essentially com es because in the ' 0 w ires, the leads are no longer free.

Sim ilarly, the tem perature and length dependences of the total cross-conductance is given by

$$G_{12} + G_{21} = \frac{1}{2} e^{2} \left(\frac{T}{T_{d}}\right)^{2 (K_{L} 1)} \left(\frac{T_{d}}{T_{d}}\right)^{2 (K_{eff} 1)} (\cos 2 N_{0+} \cos 2 N_{0})$$
(31)

This result is experimentally testable and is plotted in Fig.(4).

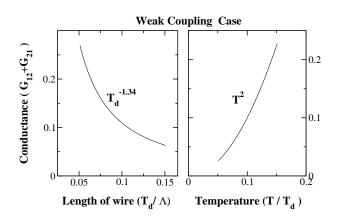


FIG.4. The dependence of the low tem perature $(T T_d)$ cross-conductance (in units of $2e^2 = h$) on T and T_d for the case of K = 5. Here $T_d = hv = k_B d$ is the tem perature equivalent of the length d of the wire. is the high energy cuto scale. The overall scale of the conductance has been adjusted by adjusting , to be within the perturbative regime. Hence, it is only the power law which is signi cant.

(ii) Strong interaction, strong coupling lim it:

For strong inter-electron interactions (K $_{eff}^{0}$ < 1) or K < 1=3, the density-density coupling term is relevant

under the RG transform ation. Connecting leads to the interacting wires changes the regime of K for which the density-density coupling is relevant from K < 1=2 to K <1=3. So from an experimental point of view, carbonnanotubes are very good candidates for testing our predictions in this limit, as its Luttinger parameter (K) ranges from 0.2 to 0.3 [1 {3]. Since renorm alises to very large values in this regime, for very long wires or at very low tem perature, the $+^{0}$ and \cdot^{0} w ires are cut and there is no transmission, except at resonance points. However, for nite temperatures and for nite length wires, as usual, we can compute the conductances as a function of the tem perature and/or length scale perturbatively. The high tem perature (T T_d) conductance scales now with $1=K_{eff}^{0}$, instead of K_{eff}^{0} as in the weak interaction case. At low tem peratures (T T_d) also, the interaction param eters get replaces by their inverses [13,16] and the direct and cross-conductances are given by

$$G \quad e^{2}t^{2} \left(\frac{T}{T_{d}}\right)^{2(1=K_{L}-1)} \left(\frac{T_{d}}{T_{d}}\right)^{2(1=K_{eff}^{0}-1)} \quad G_{12} + G_{21}$$
(32)

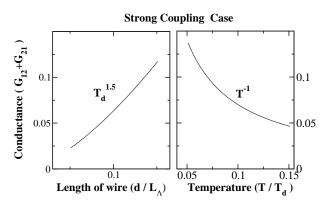


FIG.5. The dependences of the low temperature (T $T_{\rm d}$) conductance (in units of 2e^2=h) on T and $T_{\rm d}$ for the case of K = 25.

(b) Case of $U_1 \in U_2$:

However, when $U_1 \notin U_2$, it is no longer possible to tune for resonances through the $+ {}^0$ and 0 wires simultaneously due to the presence of the $N_+ N$ term in the e ective action. N_{0+} now depends on N and N_0 depends on N_+ . But it is always possible to x either N_0 or N_{0+} and tune the other wire to resonance. The condition for resonance for the $+ = {}^0$ wire is given by

$$V_{eff}(N; N;) = V_{eff}(N + 1; + \frac{P}{2}; N;)$$

(33)

and the appropriate gate voltages at which the wires get tuned to resonance is given by

$$g_{1} + g_{2} = \frac{2k_{F}d}{2} n + \frac{1}{2} - \frac{U_{1}}{4} - \frac{U_{2}}{U_{1} + U_{2}} - U_{eff}$$

$$g_{1} \quad g_{I} = -\frac{2k_{F}d}{4} - \frac{U_{1}}{U_{1} + U_{2}} n + \frac{1}{2}$$

$$-\frac{U_{1}}{4} - \frac{U_{1}}{U_{1} + U_{2}} - U_{eff}; \quad (34)$$

which gives us the deviations $\ensuremath{_1}$ and $\ensuremath{_2}$ in Figs 3 and 4 as

$$_{1} = \frac{1}{4} - \frac{U_{1} - U_{2}}{U_{1} + U_{2}} - U_{eff}$$
(35)

$$_{2} = \left(\frac{k_{\rm F} d}{2^{2}} - 1\right)_{1}$$
 (36)

Here n and m are the number of electrons on the '+ = 0 wires when they are o resonance and the ' =+ 0 wire is tuned to resonance. Since the resonance condition of one wire (say wire A) depends on the number of electrons of the other wire (wire B), unlike the case when the two wires are decoupled (U₁ = U₂), wire B clearly has to have a xed num ber of electrons - in:, it has to be o -resonance. (At resonance, the wire is degenerate for n and n + 1 electrons and hence does not have a xed num - ber of electrons. The electron number uctuates.) So the derivations of the gate voltages above for the '+ = 0 wires are valid only when the =+ wire is far from resonance. Our analysis is unable to predict conductances for U₁ \in U₂ when both the wires are near resonance.

IV.EFFECTIVE ACTION OF COUPLED DOTS

In this section, we map the elective action studied in the earlier section to the elective action of capacitively coupled quantum dots to obtain the conductance pattern for coupled dot system s.

W e note that Eq.(17) is precisely the e ective action of coupled quantum dots with charging energies U_{eff} and an interaction energy $(U_1 \quad U_2)=4$. In the absence of the interaction term, i.e., when $U_1 = U_2$, by tuning N₀ or equivalently by tuning g_i the dot states with N and N + 1 can be made degenerate. This is the lifting of the C oulom b blockade (C B) for each individual dot. The gate voltages at which both the C B's are lifted and the current through both dots is at a maximum are the same points in F ig. 3 where both the wires go through a resonance. Similarly, the gate voltages where one of the C B's is lifted is where one of the wires goes through a resonance.

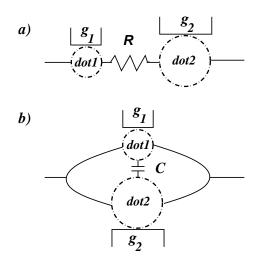


FIG.6. Schem atic diagram of (a) tunnel coupled quantum dots in series and (b) capacitively coupled quantum dots in parallel.

Note that although the elective action looks similar to the elective action for tunnel coupled quantum dots [12], there is an important di erence. Unlike the tunnelcoupled case (Fig. 4(a)), here, we have a two channel problem (Fig 4(b)). Hence, there is non-zero conductance even when only one of the C oulom b blockades is lifted. For instance, when the two dots are weakly capacitively coupled, (U₁ U₂ is sm all), we can trivially see that when the CB through dot 1 is lifted, $G_1 \notin 0$ and when the CB through dot 2 is lifted, $G_2 \notin 0$. Thus, if we measure the total conductance through both the dots, the lines of sem imaxim a are when one of the CBs is lifted. In contrast, for the tunnel coupled dots, the maxim a occur only when both C oulom b blockades are lifted.

When $U_1 \notin U_2$, we have a term mixing N_1 and N_2 . This tells us that the CB through one dot is a ected by the charge on the other dot. As in the case of wires, this means that the CBs through both dots cannot be simultaneously lifted. The lines where one of the CBs is lifted is shifted from the $U_1 = U_2$ case and as for the wires, we are unable to predict conductances at the crossing points. In contrast, the e ect of a weak interdot coupling in the tunnel coupled case is to split the maxima [17,12]. These results are depicted in Fig. 7, to show the contrast.

V.DISCUSSIONS AND CONCLUSIONS

In this paper, we have studied conductance through a pair of carbon nanotubes, which are coupled by oating gates at the beginning and end of the wires. This geometry of carbon nanotubes enables us to study how resonant tunneling conductance through one carbon nanotube is a ected by that of the other. We have obtained the conductance pattern as a function of the two gate voltages controlling the densities of the electrons in the two wires. In the plane of the two gate voltages, we nd that (for identical carbon nano-tubes), the conductance is a sem i-m axim um (goes through a single resonance) along the lines q_2 q = (m + 1=2)U and (n + 1=2) U. At the points where $q_1 + q_2 = 2k_F d=$) the two lines cross, the conductance is a maximum (goes through two resonances). In the rest of the plane, the conductance is very low (no resonance). When the two wires are not identical, the lines of sem i-m axim um (single resonance) shift to g_1 $g_2 = (2k_F d=) (U_1 U_2) = (U_1 +$ (=4) $(U_1 U_2) = (U_1 + U_2) 2U_{[4 \{6] \text{eff}}$ (n+1=2) U_2) and $q_1 + q_2 = (2k_F d=)$ (m + 1=2) (=4) (U₁ U_2)=($U_1 + U_2$) 2 U_{eff} and there is no resonance when the lines cross. We have also mapped the problem to that of two quantum dots that are capacitively coupled. The conductance through the double-dot system shows the same patterns of maxim a when both the dots are on resonance, a sem i-m axim a when one is on resonance and no conductance otherw ise.

The above analysis has been a low tem perature analysis, T $T_d = hv_{eff} = K_{eff} d$ 1K for typical wires of length d = 5 m. This is needed for coherent propagation through the wire leading to resonance features. Hence, it is the length d which plays the role of a cuto in the RG ows. A lthough, it may not be experimentally feasible to change the lengths of the wire, if it could be done, then one would expect the deviations of conductances from perfect resonance to scale as power laws of the lengths, as usually happens in LLs. The inclusion of leads also brings in non-trivial temperature dependences even in the low tem perature lim it. These may be experimentally easier to see. Thus such experiments would probe Luttinger liquid physics. More importantly, the geometry that we have studied also allows for cross-conductances, whose tem perature and length dependences also show the characteristic LL power laws. Here, however, the very existence of a 'cross' current is an interaction dependent e ect and thus provides a qualitative probe of LL physics.

Q ualitative tests of the other features that we have studied should also be experimentally feasible. Conductances through a double wire system or a capacitively coupled double dot system, should show the features that are seen in Figs. 3 and 7. There should be large differences in the conductance in the three di erent cases where 1) both the gate voltages are tuned to resonance (maxim a of conductance) 2) when one of them is tuned to resonance (sem imaxim a of conductance) and 3) when both are out of resonance (very low conductance).

F inally, this analysis can be easily extended to the case where the two wires are allowed to 'cross' at more than two points. A very sim ilar analysis shows that the system can still be decoupled in terms of 4° and 1° wires, in terms of which the problem reduces to that of Luttinger wires with multiple barriers [12]. For three crossings,

the equivalent dot geom etry involves four dots, at the four corners of a square, with tunnel couplings along the horizontalaxis and capacitive couplings along the vertical axis. These are also interesting geom etries to study [18] in the context of quantum computers.

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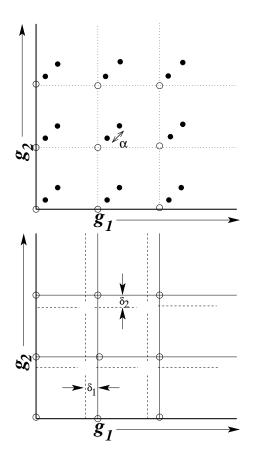


FIG. 7. Conductances in the plane of the gate voltages g_1 and g_2 for (a) tunnel coupled dots and (b) capacitively coupled dots. In the absence of coupling between the dots, the resonance maxim a form a square grid in both cases as shown by the open circles. In (a), the open circles are the only points where there is a maxim a, because both dots need to be at resonance. In (b), the solid lines indicate sem i-maxim a (where one of the dots is on resonance) and the open circles denote maxim a where both dots are at resonance. When interdot coupling is introduced, in (a), each point of resonance splits into two as shown by the solid circles. In (b), the lines of sem i-maxim a shift as shown by the dotted lines, and there are no points where both dots are at resonance.